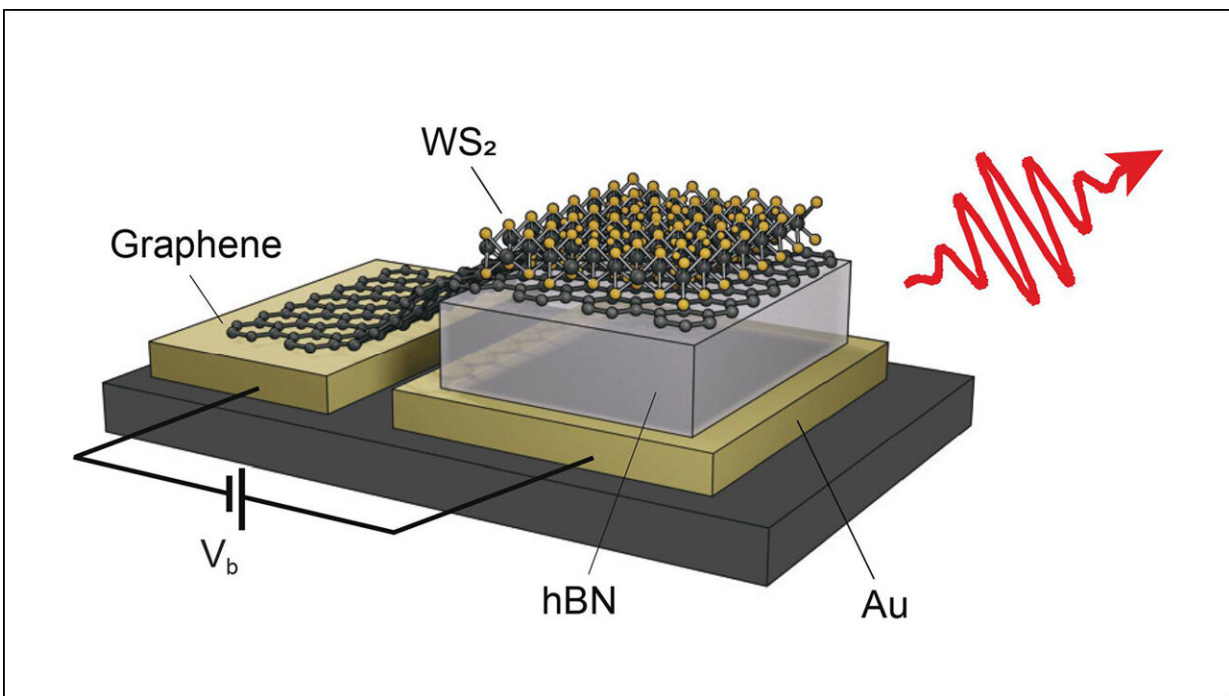


Researchers create antenna for nanoscale light sources using unusual placement of semiconductor material

July 3 2023, by Oliver Morsch



The semiconductor material (tungsten disulfide, WS₂) placed outside the tunnel junction (right) acts as an antenna and makes it possible to enhance the energy created in the tunnel junction. Credit: Sotirios Papadopoulos / ETH Zurich

The fast switching and modulation of light is at the heart, among other things, of modern data transfer, in which information is sent through

fiber optic cables in the shape of modulated light beams. It has been possible for several years now to miniaturize light modulators and to integrate them into chips, but the light sources themselves—light emitting diodes (LEDs) or lasers—still pose problems to engineers.

A team of researchers at ETH Zurich led by Prof. Lukas Novotny, together with colleagues at EMPA in Dübendorf and at ICFO in Barcelona, have now found a new mechanism by which tiny but efficient light sources could be produced in the future. The results of their research have recently been published in the journal *Nature Materials*.

Trying the unexpected

"To achieve this, we first had to try the unexpected," says Novotny. For several years he and his coworkers have been working on miniature light sources that are based on the tunnel effect. Between two electrodes (made of gold and graphene in this case) separated by an insulating material, electrons can tunnel according to the rules of quantum mechanics. Under particular circumstances—that is, if the tunnel process is inelastic, meaning that the energy of the electrons is not conserved—light can be created.

"Unfortunately, the yield of those light sources is rather poor because the radiative emission is very inefficient," explains postdoc Sotirios Papadopoulos. This emission problem is well-known in other areas of technology. In mobile phones, for instance, the chips that create the microwaves needed for transmission are only a few millimeters in size.

By contrast, the microwaves themselves have a wavelength of around 20 centimeters, which makes them a hundred times larger than the chip. To overcome this difference in size an antenna is needed (which, in modern phones, is actually no longer visible from the outside). Likewise, in the experiments of the Zurich researchers the wavelength of the light is

much larger than the [light source](#).

Semiconductor outside the tunnel junction

"One might think, then, that we were consciously looking for an antenna solution—but in reality we weren't," says Papadopoulos. Like other groups before them, the researchers were investigating layers of [semiconductor](#) materials such as tungsten disulfide with a thickness of a single atom sandwiched between the electrodes of the tunnel junction in order to create light in this way.

In principle one would assume that the optimal position should be somewhere between the two electrodes, maybe a little closer to one than to the other. Instead, the researchers tried something completely different by putting the semiconductor on top of the graphene electrode—completely outside the tunnel junction.

Surprising antenna action

Surprisingly, this apparently illogical position worked very well. The researchers found out the reason for this by varying the voltage applied to the tunnel junction and measuring the current flowing through it. This measurement showed a clear resonance, which matched a so-called exciton resonance of the semiconductor material.

Excitons are made of a positively charged hole, which corresponds to a missing electron, and an electron bound by the hole. They can be excited, for instance, by light irradiation. The exciton resonance was a clear sign that the semiconductor was not excited directly by [charge carriers](#)—after all, there were no electrons flowing through it—but rather that it absorbed the energy created in the [tunnel](#) junction and subsequently re-emitted it. In other words, it acted very much like an

antenna.

Applications in nanoscale light sources

"For now, this antenna is not very good because inside the semiconductor so-called dark excitons are created, which means that not much light is emitted," Novotny concedes. "Improving this will be our homework for the near future." If the researchers are successful in making the light emission by the semiconductor more efficient, it should be possible to create light sources that measure only a few nanometers and are, thus, a thousand times smaller than the wavelength of the light they produce.

As there are no electrons flowing through the semiconductor antenna, there are also none of the unwanted effects that typically occur at boundaries and that can reduce the efficiency. "In any case, we have opened a door to new applications," says Novotny. Trying the unexpected has evidently paid off.

More information: Lujun Wang et al, Exciton-assisted electron tunnelling in van der Waals heterostructures, *Nature Materials* (2023). [DOI: 10.1038/s41563-023-01556-7](https://doi.org/10.1038/s41563-023-01556-7)

Provided by ETH Zurich

Citation: Researchers create antenna for nanoscale light sources using unusual placement of semiconductor material (2023, July 3) retrieved 29 April 2024 from <https://phys.org/news/2023-07-antenna-nanoscale-sources-unusual-placement.html>

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